imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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RGTV60TK65 650V 30A Field Stop Trench IGBT

V _{CES}	650V
I _{C (100°C)}	20A
V _{CE(sat) (Typ.)}	1.5V@I _c =30A
PD	76W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching & Low Switching Loss
- 3) Short Circuit Withstand Time 2µs
- 4) Pb free Lead Plating ; RoHS Compliant

Applications

Solar Inverter

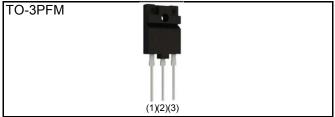
UPS

Welding

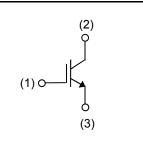
IH

PFC

Outline



Inner Circuit





Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTV60TK65

•Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

			,	
Paramet	Symbol	Value	Unit	
Collector - Emitter Voltage	V _{CES}	650	V	
Gate - Emitter Voltage	V _{GES}	±30	V	
Collector Current	$T_c = 25^{\circ}C$	Ι _C	33	А
Collector Current	T _C = 100°C	Ι _C	20	А
Pulsed Collector Current	ا _{CP} *1	120	А	
$T_c = 25^{\circ}C$		P _D	76	W
Power Dissipation	$T_{\rm C}$ = 100°C	P _D	38	W
Operating Junction Temperate	Tj	-40 to +175	°C	
Storage Temperature		T _{stg}	–55 to +175	°C

*1 Pulse width limited by T_{jmax}.

•Thermal Resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	1.97	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Symbol Conditions		Values			
Farameter	Symbol Conditions		Min.	Тур.	Max.	Unit	
Collector - Emitter Breakdown Voltage	BV _{CES}	I _C = 10μΑ, V _{GE} = 0V	650	-	-	V	
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	-	-	10	μA	
Gate - Emitter Leakage Current	I _{GES}	V _{GE} = ±30V, V _{CE} = 0V	-	-	±200	nA	
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	V _{CE} = 5V, I _C = 21.0mA	5.0	6.0	7.0	V	
Collector - Emitter Saturation Voltage	V _{CE(sat)}	I _C = 30A, V _{GE} = 15V T _j = 25°C T _j = 175°C	-	1.5 1.85	1.9 -	V	

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Demonster	Symbol	Openditiens	Values			1.1
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V	-	1730	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	74	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	30	-	
Total Gate Charge	Qg	V _{CE} = 400V	-	64	-	
Gate - Emitter Charge	Q _{ge}	I _C = 30A	-	14	-	nC
Gate - Collector Charge	Q _{gc}	V _{GE} = 15V	-	24	-	
Turn - on Delay Time	t _{d(on)}	I _C = 30A, V _{CC} = 400V	-	33	-	
Rise Time	t _r	V _{GE} = 15V, R _G = 10Ω	-	12	-	20
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	105	-	ns
Fall Time	t _f	Inductive Load	-	40	-	
Turn - on Switching Loss	E _{on}	*E _{on} includes diode	-	0.57	-	
Turn - off Switching Loss	E _{off}	reverse recovery	-	0.50	-	mJ
Turn - on Delay Time	t _{d(on)}	I _C = 30A, V _{CC} = 400V	-	32	-	
Rise Time	t _r	V _{GE} = 15V, R _G = 10Ω	-	13	-	20
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	121	-	ns
Fall Time	t _f	Inductive Load	-	80	-	
Turn - on Switching Loss	E _{on}	*E _{on} includes diode	-	0.63	-	
Turn - off Switching Loss	E _{off}	reverse recovery	-	0.72	-	mJ
		I _C = 120A, V _{CC} = 520V				
Reverse Bias Safe Operating Area	RBSOA	V _P = 650V, V _{GE} = 15V	FU	LL SQUA	RE	-
,		R _G = 100Ω, T _j = 175°C				
		$V_{CC} \leq 360V$				
Short Circuit Withstand Time	t _{sc}	V _{GE} = 15V	2	-	-	μs
		T _j = 25°C				

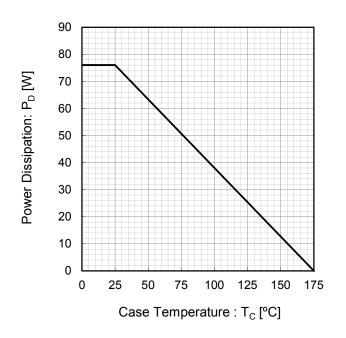


Fig.1 Power Dissipation vs. Case Temperature F

Fig.2 Collector Current vs. Case Temperature

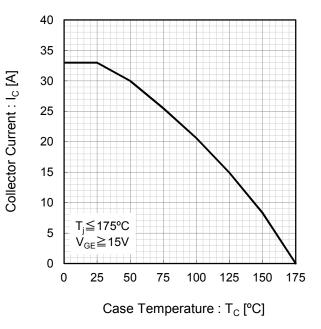
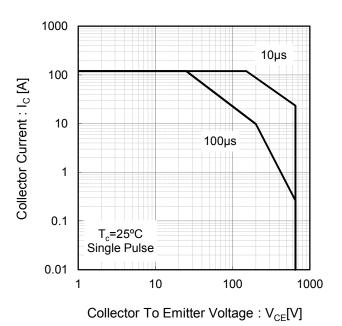
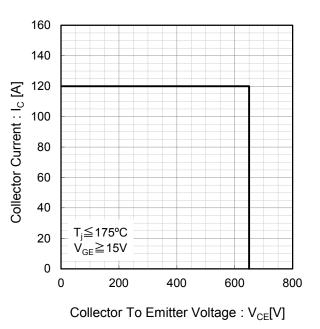


Fig.3 Forward Bias Safe Operating Area

Fig.4 Reverse Bias Safe Operating Area





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•Electrical Characteristic Curves

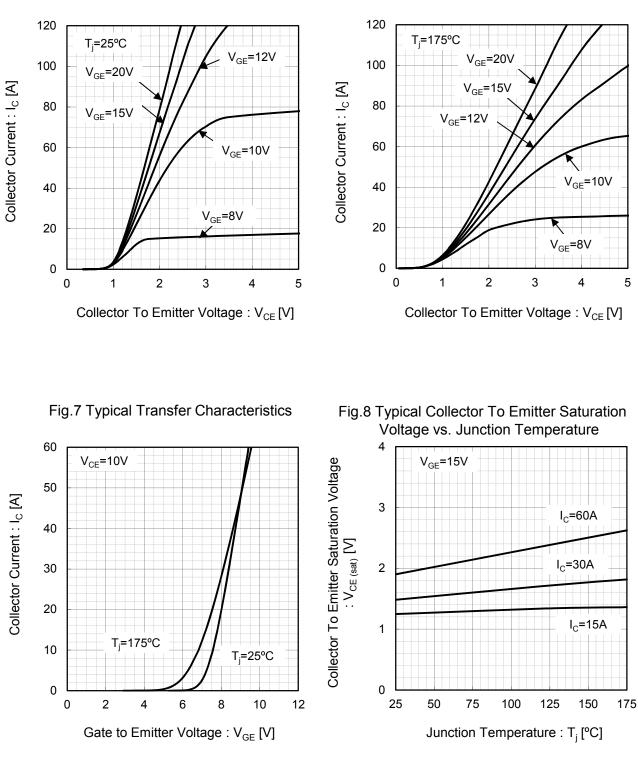
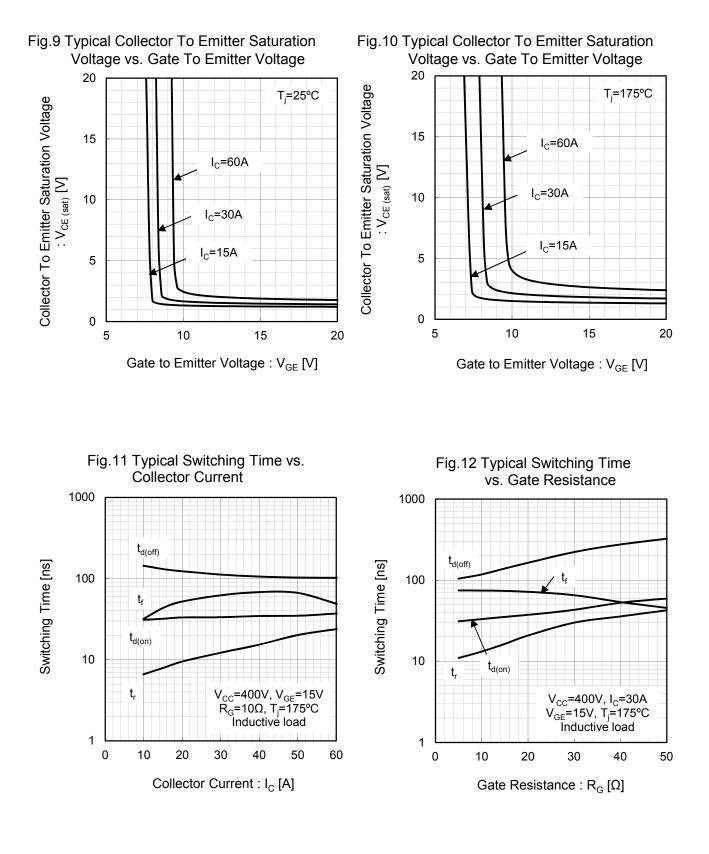
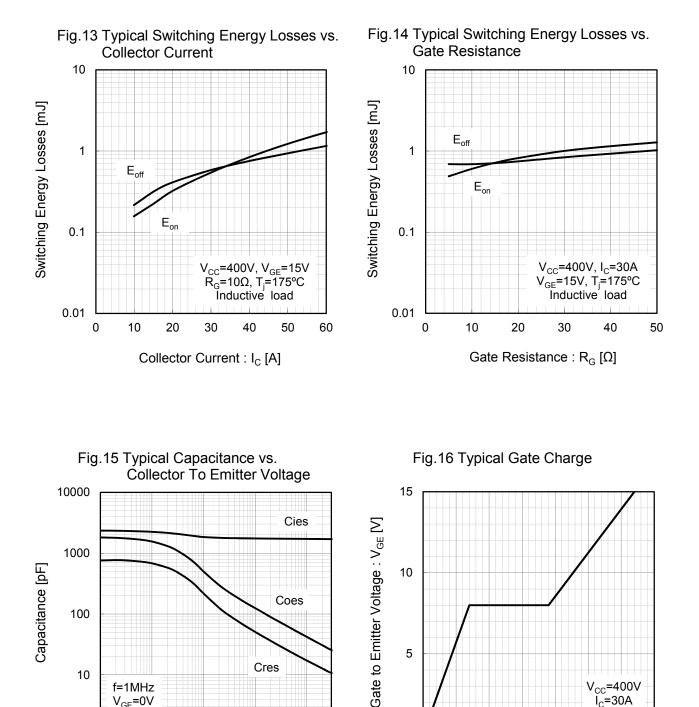


Fig.5 Typical Output Characteristics

Fig.6 Typical Output Characteristics





10

1

0.01

f=1MHz V_{GE}=0V

Ti=225℃

0.1

1

Collector To Emitter Voltage : $V_{CE}[V]$

V_{CC}=400V I_C=30A

, =25°C

60

70

5

0

0

10

20

30

40

Gate Charge : Q_q[nC]

50

Cres

10

100

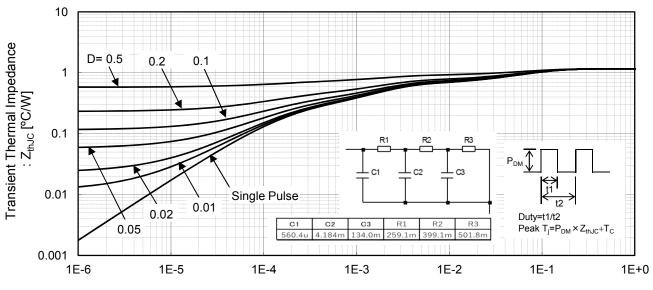
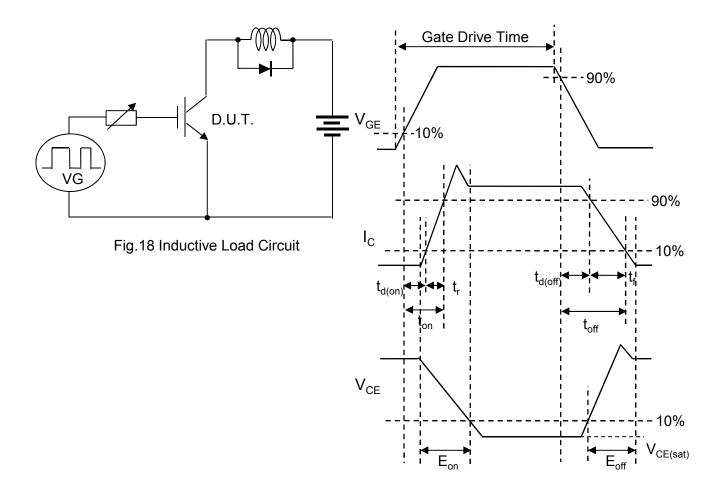
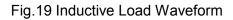


Fig.17 Typical IGBT Transient Thermal Impedance

Pulse Width : t1[s]

•Inductive Load Switching Circuit and Waveform





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RGTV60TK65 - Web Page

Part Number	RGTV60TK65
Package	TO-3PFM
Unit Quantity	450
Minimum Package Quantity	30
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes